

LIM-262-#

pyroelectric multispectral detector

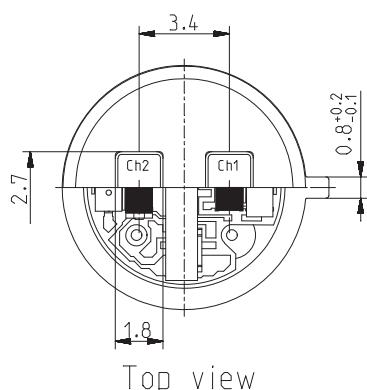
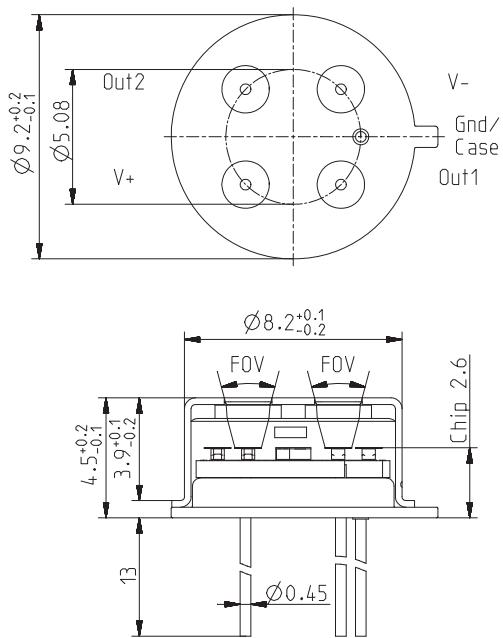
Description:

dual channel; TO39 housing; small chip size; thermal compensation; OpAmp; current mode; feedback 100GOhm;

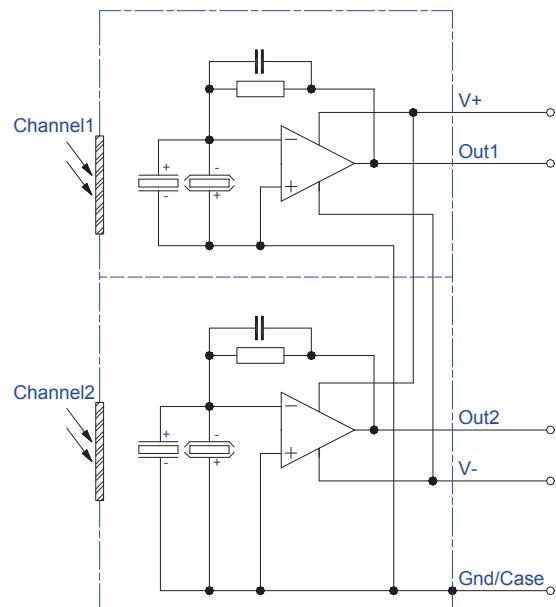


HOUSING:

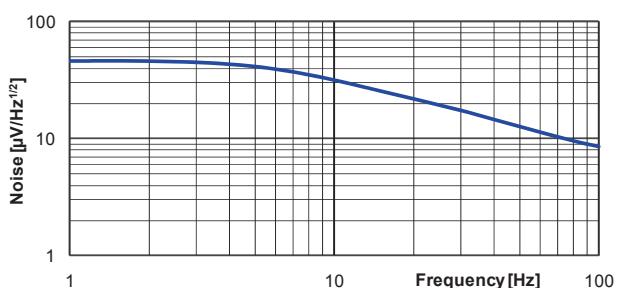
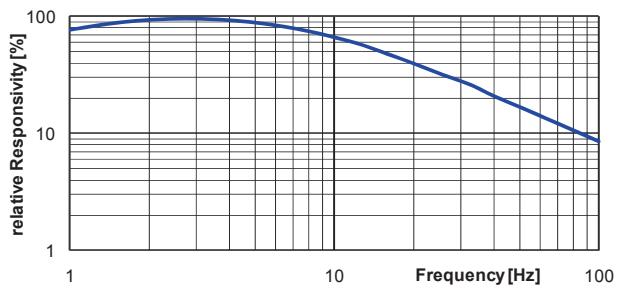
T039 4+1Pin
Bottom view



PIN ASSIGNMENT:



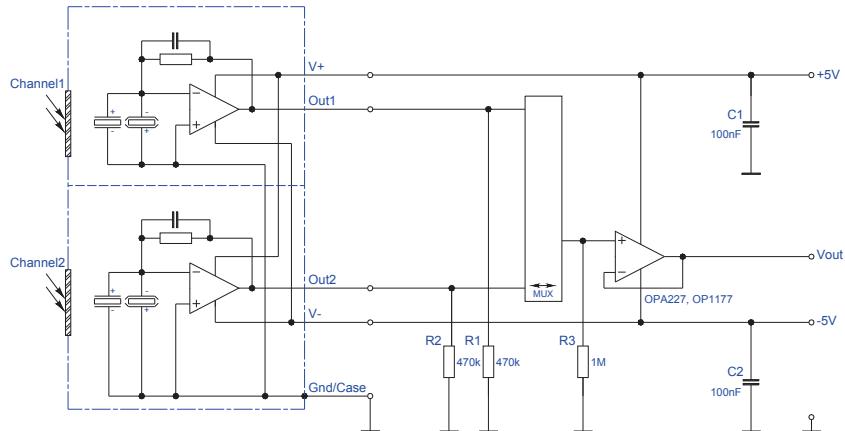
FREQUENCY RESPONSE:



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TEST CIRCUIT:



PARAMETERS:

Aperture size	nom	$\varnothing 6.0$ mm, single channel 2.7×1.8 mm 2
Element size / type	nom	1.0×1.8 mm 2 lithium-tantalate with black layer
Thermal time constant	typ	150 ms
Feedback resistor	nom	$100 \text{ GOhm} \pm 20\%$
Feedback capacitor	nom	$0.2 \text{ pF} \pm 0.1 \text{ pF}$
Polarity	nom	negative signal by positive IR flux change
Voltage responsivity (rms) {500 K, 10 Hz, 25 °C, without filter/window}	min	60,000 V/W
Noise density (rms) {10 Hz, BW 1 Hz, 25 °C}	max	35 $\mu\text{V}/(\text{sqrt}[Hz])$
Detectivity {500 K, 10 Hz, 1 Hz, 25 °C, without filter/window}	typ	$4.5 \times 10^8 \text{ cm}(\text{sqrt}[Hz])/W$
CMOS operational amplifier	nom	OpAmp2
Supply voltage V+ - V-	max	16 V
Operating supply voltage V+ / V-		+2.2 ... 8.0 V / -2.2 ... -8.0 V
Recommended supply voltage V+ / V-	nom	V+ = +5 V; V- = -5 V
Supply current {output load 1 MOhm}	max	150 μA
Offset voltage {25 °C; output load 1 MOhm}		-5 mV ... +5 mV
Optimal output load	nom	330 kOhm
Absolute output current	max	± 0.4 mA
Operating / Storage temperature	nom	-25 ... +85 °C
IR window		Combinations of all InfraTec standard narrow band pass filters are available. Customized filters upon request.
Filter sizes	nom	rectangular filters: $(3.50 \pm 0.1 \times 2.50 \pm 0.1)mmcircular filters: not applicablestandard thickness: 0.50 mm \pm 0.2/-0.1 mmthickness range 0.70 ... 1.10 mm on request$
Field of View	min	CaF ₂ or BaF ₂ ; 0.4 mm thick: not applicable Silicon substrate; 0.5 mm thick: 30°